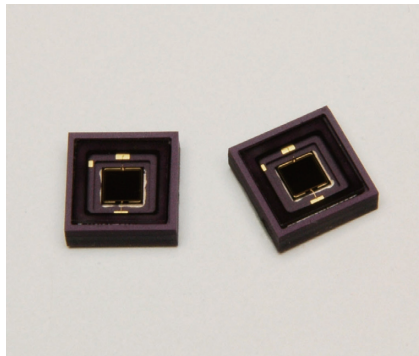


# Two-color detector



K12729-010K

**Wide spectral response range: 0.9 to 2.55  $\mu\text{m}$**   
**Compact ceramic package**

The K12729-010K is a two-color detector in a compact ceramic package, covering a wide spectral response range. Like the current K11908-010K, it incorporates two InGaAs PIN photodiodes with different spectral response, along the same optical axis. It features low noise and low dark current and supports reflow soldering.

## Features

- Wide spectral response range
- Compact, low noise, low dark current
- Supports reflow soldering

## Applications

- Spectrophotometers
- Radiation thermometers

## Structure

Parameter	Symbol	Condition	Specification	Unit
Window material	-		Borosilicate glass	-
Package	-		Ceramic	-
Photosensitive area	-	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ )	2.4 × 2.4	mm
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ )	$\phi 1.0$	

## Absolute maximum ratings

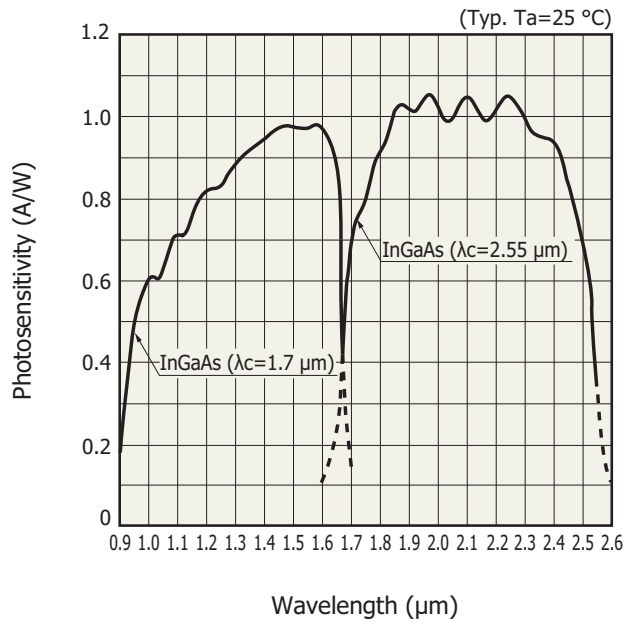
Parameter	Symbol	Condition	Value	Unit
Reverse voltage	$V_R \text{ max}$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $T_a=25 \text{ }^\circ\text{C}$	2	V
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $T_a=25 \text{ }^\circ\text{C}$	1	
Operating temperature	$T_{opr}$	No condensation	-20 to +70	$^\circ\text{C}$
Storage temperature	$T_{stg}$	No condensation	-20 to +85	$^\circ\text{C}$

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

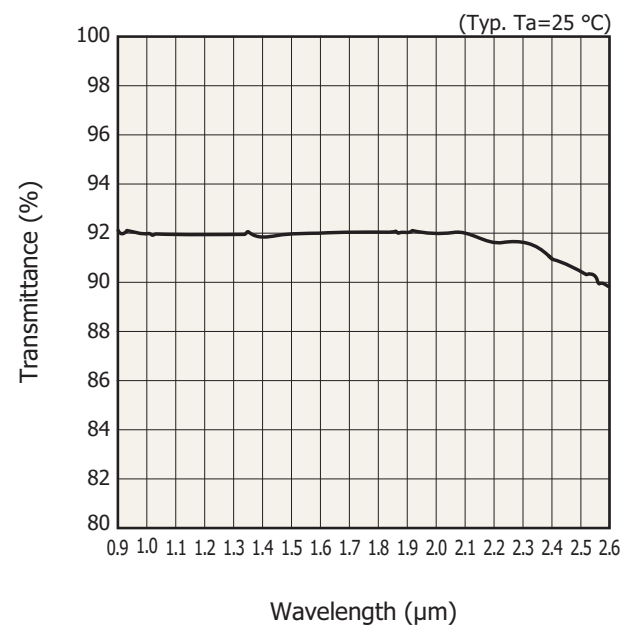
## Electrical and optical characteristics ( $T_a=25 \text{ }^\circ\text{C}$ )

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectral response range	$\lambda$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ )	-	0.9 to 1.7	-	$\mu\text{m}$
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ )	-	1.7 to 2.55	-	
Peak sensitivity wavelength	$\lambda_p$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ )	-	1.55	-	$\mu\text{m}$
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ )	-	2.1	-	
Photosensitivity	S	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $\lambda=\lambda_p$	0.85	0.95	-	A/W
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $\lambda=\lambda_p$	0.7	1.0	-	
Dark current	$I_D$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $V_R=10 \text{ mV}$	-	1	10	nA
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $V_R=10 \text{ mV}$	-	0.7	3.5	$\mu\text{A}$
Cutoff frequency	$f_c$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), -3 dB $V_R=0 \text{ V}$ , $R_L=50 \Omega$	1	2	-	MHz
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), -3 dB $V_R=0 \text{ V}$ , $R_L=50 \Omega$	2	6	-	
Terminal capacitance	$C_t$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $V_R=0 \text{ V}$ , $f=1 \text{ MHz}$	-	1.5	2.5	nF
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $V_R=0 \text{ V}$ , $f=1 \text{ MHz}$	-	0.5	1	
Shunt resistance	Rsh	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $V_R=10 \text{ mV}$	1	10	-	$\text{M}\Omega$
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $V_R=10 \text{ mV}$	2.8	14	-	k $\Omega$
Detectivity	$D^*$	InGaAs ( $\lambda_c=1.7 \mu\text{m}$ ), $\lambda=\lambda_p$	$1 \times 10^{12}$	$5 \times 10^{12}$	-	$\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$
		InGaAs ( $\lambda_c=2.55 \mu\text{m}$ ), $\lambda=\lambda_p$	$2 \times 10^{10}$	$7 \times 10^{10}$	-	

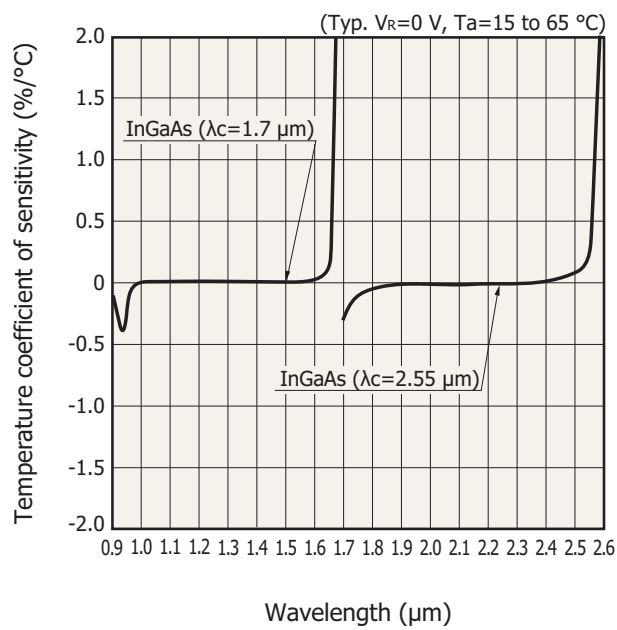
**Spectral response**



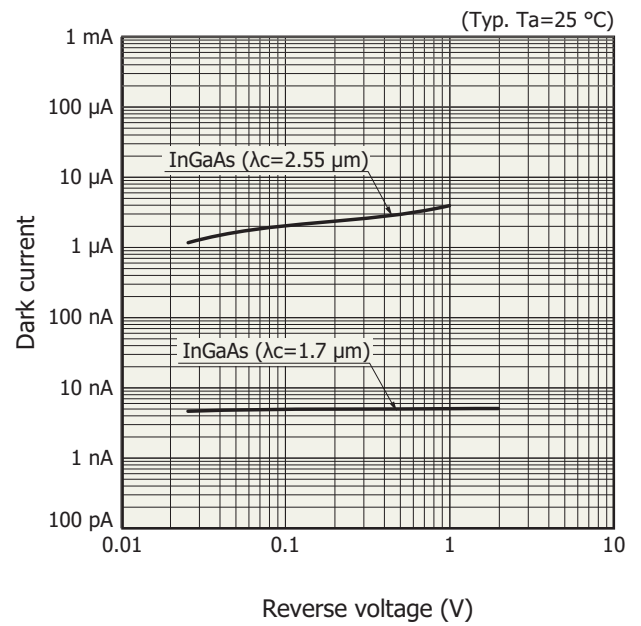
**Spectral transmittance of window material**



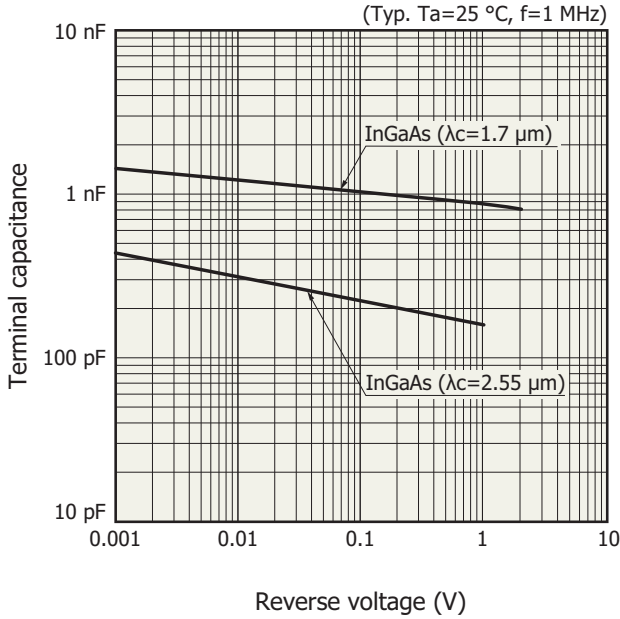
**Temperature characteristics of sensitivity**



**Dark current vs. reverse voltage**

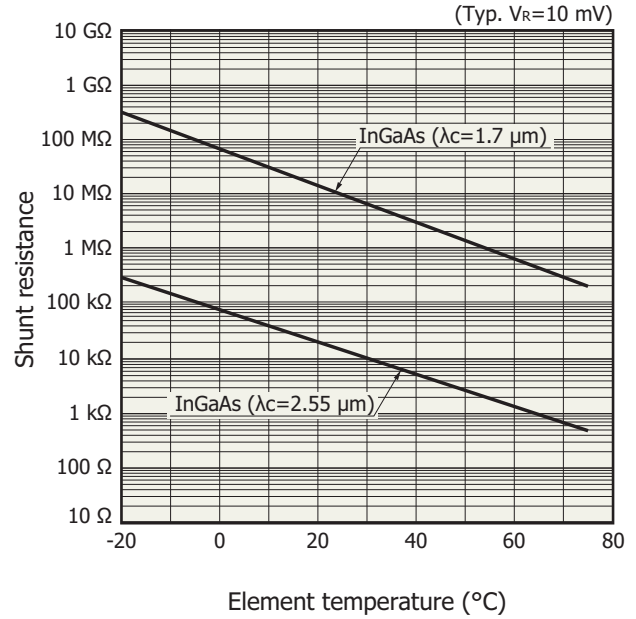


Terminal capacitance vs. reverse voltage



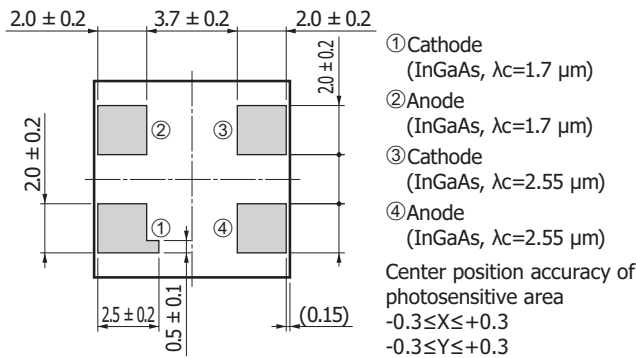
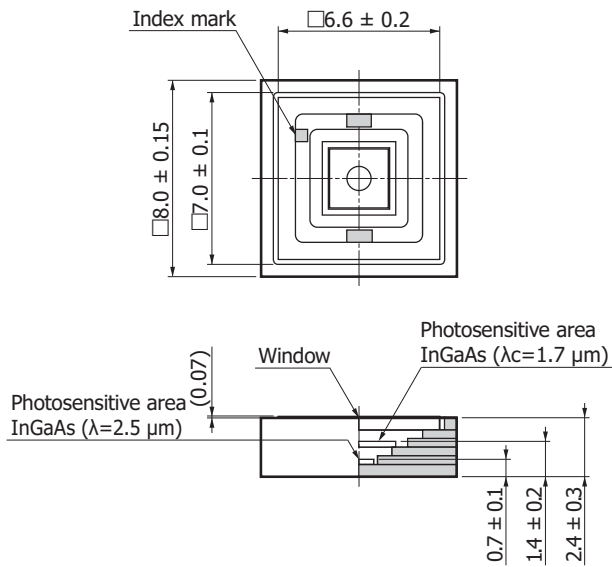
KIRD0604EA

Shunt resistance vs. element temperature



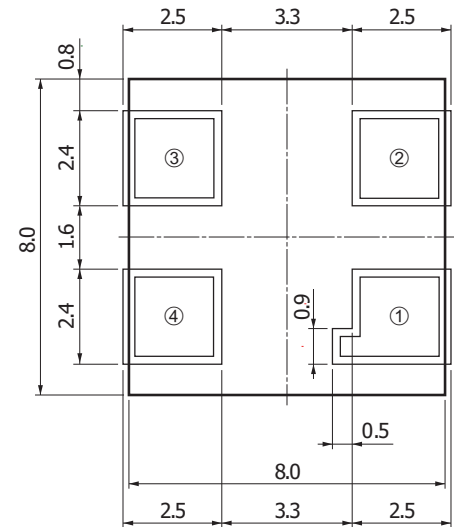
KIRD0605EA

Dimensional outline (unit: mm)

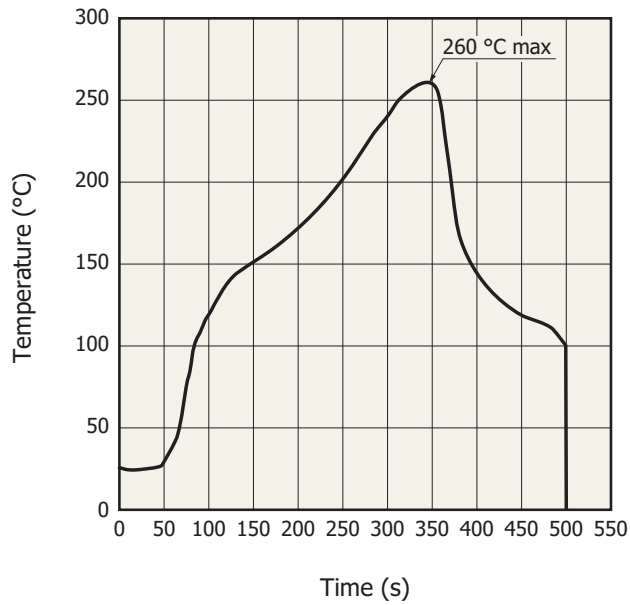


KIRDA0244EA

Recommended land mark pattern (unit: mm)



KIRD0121EA

**Measured example of temperature profile with our hot-air reflow oven for product testing**

K1RDC0122EA

- After unpacking, store the device in an environment at a temperature range of 5 to 30 °C and a humidity of 60% or less, and perform reflow soldering within 4 weeks.
- The thermal stress applied to the device during reflow soldering varies depending on the circuit board and the reflow oven that is used.
- When setting the reflow conditions, verify that the reliability of the device is not compromised by the reflow soldering process.

## Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

### ■Precautions

- Notice
- Metal, ceramic, plastic packages

### ■Technical information

- Infrared detector / Technical information

Information described in this material is current as of August, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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